

TPS3808 低静态电流、可编程延迟监控电路

1 特性

- 上电复位发生器具有可调节延迟时间：1.25ms 至 10s
- 极低静态电流：2.4 μA (典型值)
- 高阈值精度：0.5% (典型值)
- 提供适用于标准电压轨的 0.9V 至 5V 固定阈值电压且可调节电压低至 0.4V
- 手动复位 ($\overline{\text{MR}}$) 输入
- 漏极开路复位输出
- 温度范围：-40°C 至 125°C
- 小型 SOT-23 和 2mm $\times$ 2mm WSON 封装

2 应用

- DSP 或微控制器应用
- 笔记本电脑和台式机
- PDA 和手持式产品
- 便携式和电池供电类产品
- FPGA 和 ASIC 应用

3 说明

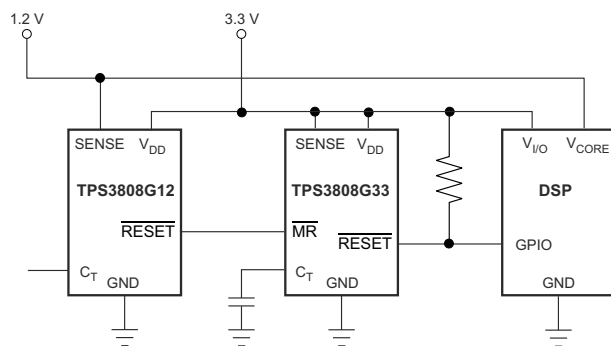
TPS3808 系列微处理器监控电路可监控从 0.4V 至 5V 的系统电压，并在 SENSE 电压降至预设阈值以下或手动复位 ($\overline{\text{MR}}$) 引脚降至逻辑低电平时，将开漏 RESET 信号置为有效。在 SENSE 电压和手动复位 ($\overline{\text{MR}}$) 返回值超出相应阈值时，RESET 输出将在用户可调延迟时间内保持低电平。

TPS3808 器件使用精密电压基准，可在 $V_{\text{IT}} \leq 3.3\text{V}$ 时达到 0.5% 的阈值精度。通过断开 C_T 引脚，可将复位延迟时间设置为 20ms；通过使用电阻将 C_T 引脚连接至 V_{DD} ，可将复位延迟时间设置为 300ms，或通过将 C_T 引脚连接到外部电容器，用户可在 1.25ms 至 10s 之间调整复位延迟时间。TPS3808 器件具有超低的典型静态电流，为 2.4 μA ，因此非常适合电池供电类应用。它采用 SOT-23 和 2mm $\times$ 2mm WSON 封装，额定工作温度范围为 -40°C 至 125°C (T_J)。

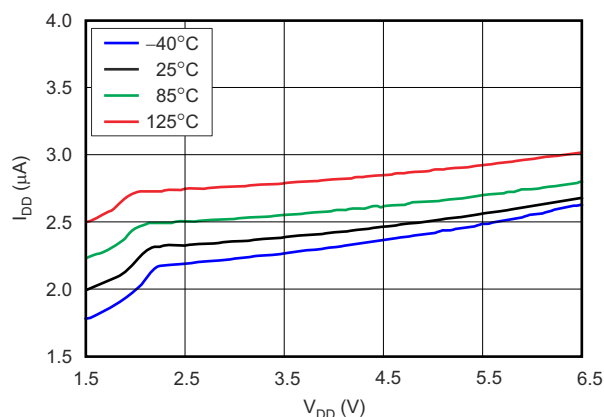
器件信息

器件型号	封装 ⁽¹⁾	封装尺寸 (标称值)
TPS3808	SOT-23 (6)	2.90mm $\times$ 1.60mm
	WSON (6)	2.00mm $\times$ 2.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



典型应用



电源电流与电源电压间的关系



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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision L (September 2020) to Revision M (March 2023)	Page
• Updated <i>Device Voltage Thresholds</i> footnote.....	3
• Updated <i>Thermal Information</i>	5
Changes from Revision K (October 2015) to Revision L (September 2020)	Page
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
Changes from Revision J (August 2008) to Revision K (October 2015)	Page
• 添加了 <i>ESD</i> 等级表、特性说明部分、器件功能模式、应用和实现部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分。移动了开关特性表、时序图和相关的真值表。.....	1
• Changed 图 9-1; removed capacitor shown on C _T	14

5 Device Voltage Thresholds

The following table shows the nominal rail to be monitored and the corresponding threshold voltage of the device.

PART NUMBER	NOMINAL SUPPLY VOLTAGE ⁽¹⁾	THRESHOLD VOLTAGE (V _{IT})
TPS3808G01	Adjustable	0.405 V
TPS3808G09	0.9 V	0.84 V
TPS3808G12	1.2 V	1.12 V
TPS3808G125	1.25 V	1.16 V
TPS3808G15	1.5 V	1.40 V
TPS3808G18	1.8 V	1.67 V
TPS3808G19	1.9 V	1.77 V
TPS3808G25	2.5 V	2.33 V
TPS3808G30	3 V	2.79 V
TPS3808G33	3.3 V	3.07 V
TPS3808G50	5 V	4.65 V

(1) Please contact TI for availability of other threshold options.

6 Pin Configuration and Functions

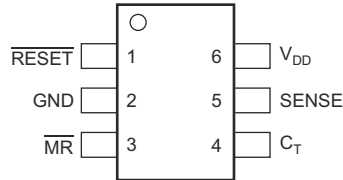


图 6-1. DBV Package 6-Pin SOT-23 Top View

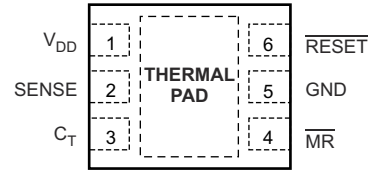


图 6-2. DRV Package 6-Pin (2.00 mm × 2.00 mm) WSON With Thermal Pad Top View

表 6-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	SOT-23	WSON		
C_T	4	3	I	Reset period programming pin. Connecting this pin to V_{DD} through a 40-k Ω to 200-k Ω resistor or leaving it open results in fixed delay times (see §7.5). Connecting this pin to a ground referenced capacitor ≥ 100 pF gives a user-programmable delay time. See §8.3.2 for more information.
GND	2	5	—	Ground
$\overline{MR}$	3	4	I	Driving the manual reset pin ($\overline{MR}$) low asserts $\overline{RESET}$. $\overline{MR}$ is internally tied to V_{DD} by a 90-k Ω pull-up resistor.
$\overline{RESET}$	1	6	O	$\overline{RESET}$ is an open-drain output that is driven to a low-impedance state when $\overline{RESET}$ is asserted (either the SENSE input is lower than the threshold voltage (V_{IT}) or the $\overline{MR}$ pin is set to a logic low). $\overline{RESET}$ remains low (asserted) for the reset period after both SENSE is above V_{IT} and $\overline{MR}$ is set to a logic high. A pull-up resistor from 10 k Ω to 1 M Ω should be used on this pin, and allows the reset pin to attain voltages higher than V_{DD} .
SENSE	5	2	I	This pin is connected to the voltage to be monitored. If the voltage at this terminal drops below the threshold voltage V_{IT} , then $\overline{RESET}$ is asserted.
V_{DD}	6	1	I	Supply voltage. It is good analog design practice to place a 0.1- μ F ceramic capacitor close to this pin.
Thermal Pad	—	Pad	—	Thermal Pad. Connect to ground plane to enhance thermal performance of package.

7 Specifications

7.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Voltage	V _{DD}	- 0.3	7	V
	V _{CT}	- 0.3	V _{DD} + 0.3	V
	V _{RESET} , V _{MR} , V _{SENSE}	- 0.3	7	V
Current	RESET pin	- 5	5	mA
Temperature	Operating junction, T _J ⁽²⁾	- 40	150	°C
	Storage, T _{stg}	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) As a result of the low dissipated power in this device, it is assumed that T_J = T_A.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{DD}	Input supply range	1.7		6.5	V
V _{SENSE}	SENSE pin voltage	0		6.5	V
V _(CT)	C _T pin voltage			V _{DD}	V
V _{MR}	MR pin voltage	0		6.5	V
V _{RESET}	RESET pin voltage	0		6.5	V
I _{RESET}	RESET pin current	0.0003		5	mA

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS3808		UNIT
		DBV (SOT-23)	DRV (WSON)	
		6 PINS	6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	180.9	178.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	117.8	95.6	°C/W
R _{θJB}	Junction-to-board thermal resistance	27.8	135	°C/W
ψ _{JT}	Junction-to-top characterization parameter	18.9	6.3	°C/W
ψ _{JB}	Junction-to-board characterization parameter	27.3	136.6	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	7.3	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

7.5 Electrical Characteristics

$1.7\text{ V} \leq V_{DD} \leq 6.5\text{ V}$, $R_{LRESET} = 100\text{ k}\Omega$, $C_{LRESET} = 50\text{ pF}$, over operating temperature range ($T_J = -40^\circ\text{C}$ to 125°C), unless otherwise noted. Typical values are at $T_J = 25^\circ\text{C}$ ⁽¹⁾.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{DD}	Input supply range	$-40^\circ\text{C} < T_J < 125^\circ\text{C}$	1.7		6.5	V
		$0^\circ\text{C} < T_J < 85^\circ\text{C}$	1.65		6.5	V
I_{DD}	Supply current (current into V_{DD} pin)	$V_{DD} = 3.3\text{ V}$, $\overline{\text{RESET}}$ not asserted $\overline{\text{MR}}$, $\overline{\text{RESET}}$, C_T open		2.4	5	μA
		$V_{DD} = 6.5\text{ V}$, $\overline{\text{RESET}}$ not asserted $\overline{\text{MR}}$, $\overline{\text{RESET}}$, C_T open		2.7	6	
V_{OL}	Low-level output voltage	$1.3\text{ V} \leq V_{DD} < 1.8\text{ V}$, $I_{OL} = 0.4\text{ mA}$			0.3	V
		$1.8\text{ V} \leq V_{DD} \leq 6.5\text{ V}$, $I_{OL} = 1\text{ mA}$			0.4	
V_{POR}	Power-up reset voltage ⁽²⁾	$V_{OL}(\text{max}) = 0.2\text{ V}$, $I_{RESET} = 15\text{ }\mu\text{A}$			0.8	
V_{IT}	Negative-going input threshold accuracy	TPS3808G01		-2%	±1%	2%
		$V_{IT} \leq 3.3\text{ V}$		-1.5%	±0.5%	1.5%
		$3.3\text{ V} < V_{IT} \leq 5.0\text{ V}$		-2%	±1%	2%
		$V_{IT} \leq 3.3\text{ V}$	$-40^\circ\text{C} < T_J < 85^\circ\text{C}$	-	±0.5%	1.25%
		$3.3\text{ V} < V_{IT} \leq 5.0\text{ V}$	$-40^\circ\text{C} < T_J < 85^\circ\text{C}$	-1.5%	±0.5%	1.5%
V_{HYS}	Hysteresis on V_{IT} pin	TPS3808G01		1.5%	3%	V_{IT}
		Fixed versions		1%	2.5%	
R_{MR}	$\overline{\text{MR}}$ Internal pullup resistance		70	90		$\text{k}\Omega$
I_{SENSE}	Input current at SENSE pin	TPS3808G01	$V_{SENSE} = V_{IT}$	-25	25	nA
		Fixed versions	$V_{SENSE} = 6.5\text{ V}$	1.7		μA
I_{OH}	$\overline{\text{RESET}}$ leakage current	$V_{RESET} = 6.5\text{ V}$, $\overline{\text{RESET}}$ not asserted			300	nA
C_{IN}	Input capacitance, any pin	C_T pin	$V_{IN} = 0\text{ V}$ to V_{DD}	5		pF
		Other pins	$V_{IN} = 0\text{ V}$ to 6.5 V	5		
V_{IL}	$\overline{\text{MR}}$ logic low input		0	0.3 V_{DD}		V
V_{IH}	$\overline{\text{MR}}$ logic high input		0.7 V_{DD}		V_{DD}	

(1) The lowest supply voltage (V_{DD}) at which $\overline{\text{RESET}}$ becomes active. $T_{rise(VDD)} \geq 15\text{ }\mu\text{s/V}$.

(2) R_{LRESET} and C_{LRESET} are the resistor and capacitor connected to the RESET pin.

7.6 Switching Characteristics

$1.7\text{ V} \leq V_{DD} \leq 6.5\text{ V}$, $R_{LRESET} = 100\text{ k}\Omega$, $C_{LRESET} = 50\text{ pF}$, over operating temperature range ($T_J = -40^\circ\text{C}$ to 125°C), unless otherwise noted. Typical values are at $T_J = 25^\circ\text{C}$.⁽¹⁾

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _w	Input pulse width to RESET	SENSE	V _{IH} = 1.05 V _{IT} , V _{IL} = 0.95 V _{IT}		20			μ s
		MR	V _{IH} = 0.7 V _{DD} , V _{IL} = 0.3 V _{DD}		0.001			
t _d	RESET delay time	C _T = Open	See 图 7-1		12	20	28	ms
		C _T = V _{DD}			180	300	420	
		C _T = 100 pF			0.75	1.25	1.75	
		C _T = 180 nF			0.7	1.2	1.7	s
Propagation delay		MR to RESET	V _{IH} = 0.7 V _{DD} , V _{IL} = 0.3 V _{DD}		150			ns
High-to-low level RESET delay		SENSE to RESET	V _{IH} = 1.05 V _{IT} , V _{IL} = 0.95 V _{IT}		20			μ s

(1) R_{LRESET} and C_{LRESET} are the resistor and capacitor connected to the RESET pin.

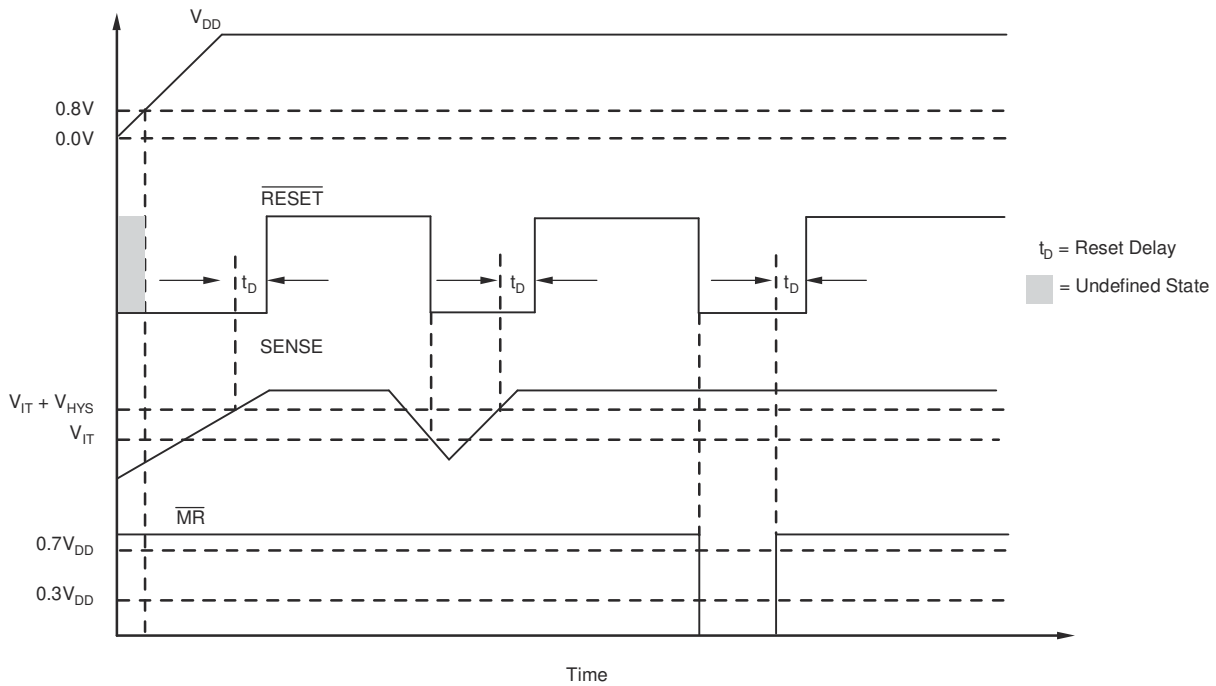


图 7-1. TPS3808 Timing Diagram Showing $\overline{\text{MR}}$ and SENSE Reset Timing

7.7 Typical Characteristics

At $T_J = 25^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$, $R_{L\text{RESET}} = 100\text{ k}\Omega$, and $C_{L\text{RESET}} = 50\text{ pF}$, unless otherwise noted.

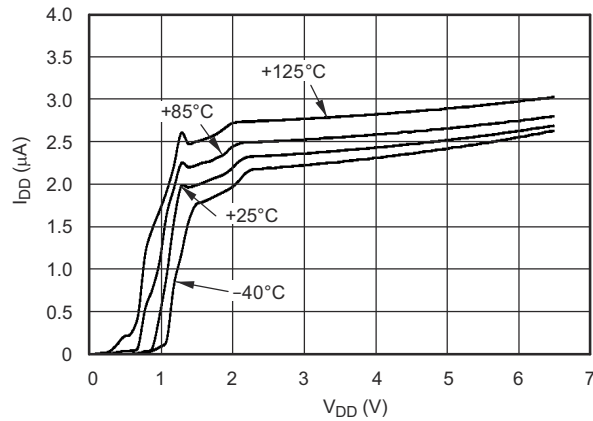


图 7-2. Supply Current vs Supply Voltage

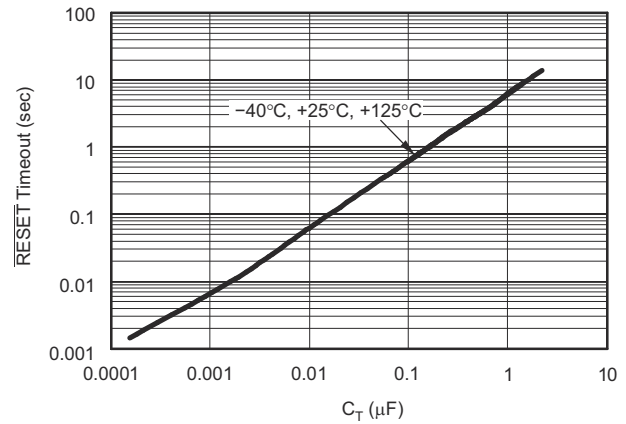


图 7-3. $\overline{\text{RESET}}$ Time-Out Period vs C_T

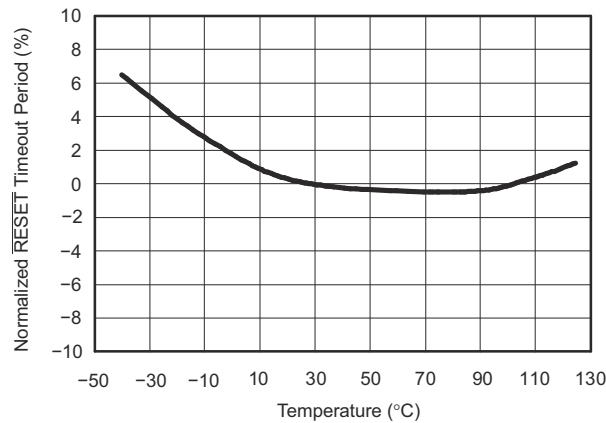


图 7-4. Normalized $\overline{\text{RESET}}$ Time-Out Period vs Temperature ($C_T = \text{Open}$, $C_T = V_{DD}$, $C_T = \text{Any}$)

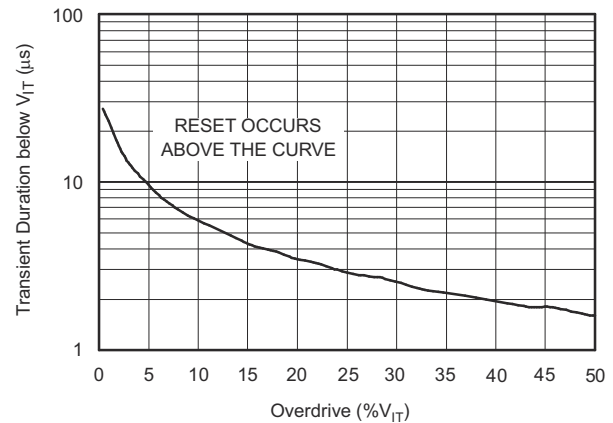


图 7-5. Maximum Transient Duration at Sense vs Sense Threshold Overdrive Voltage

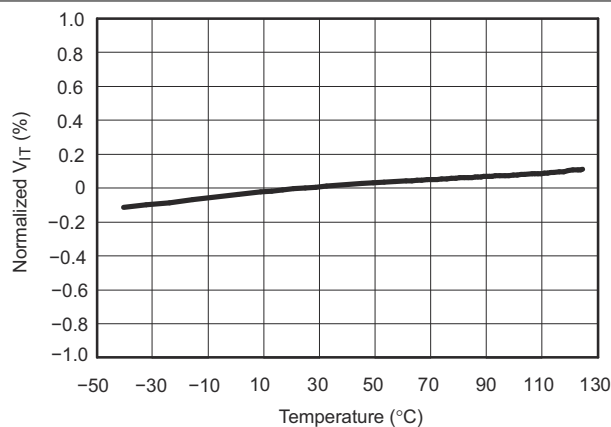


图 7-6. Normalized Sense Threshold Voltage (V_{IT}) vs Temperature

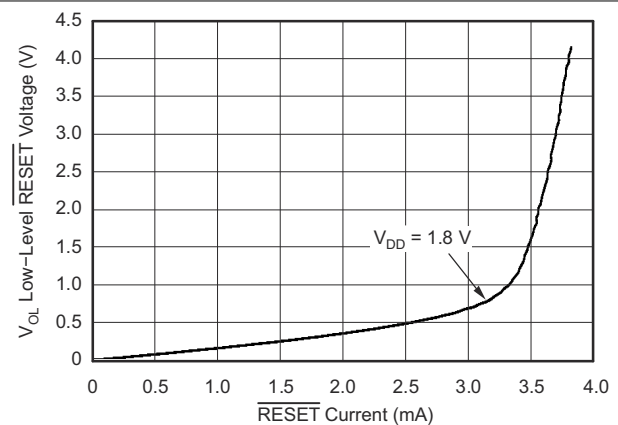


图 7-7. Low-Level $\overline{\text{RESET}}$ Voltage vs $\overline{\text{RESET}}$ Current

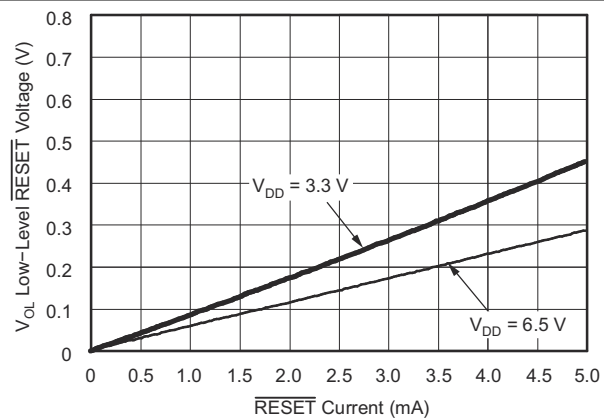


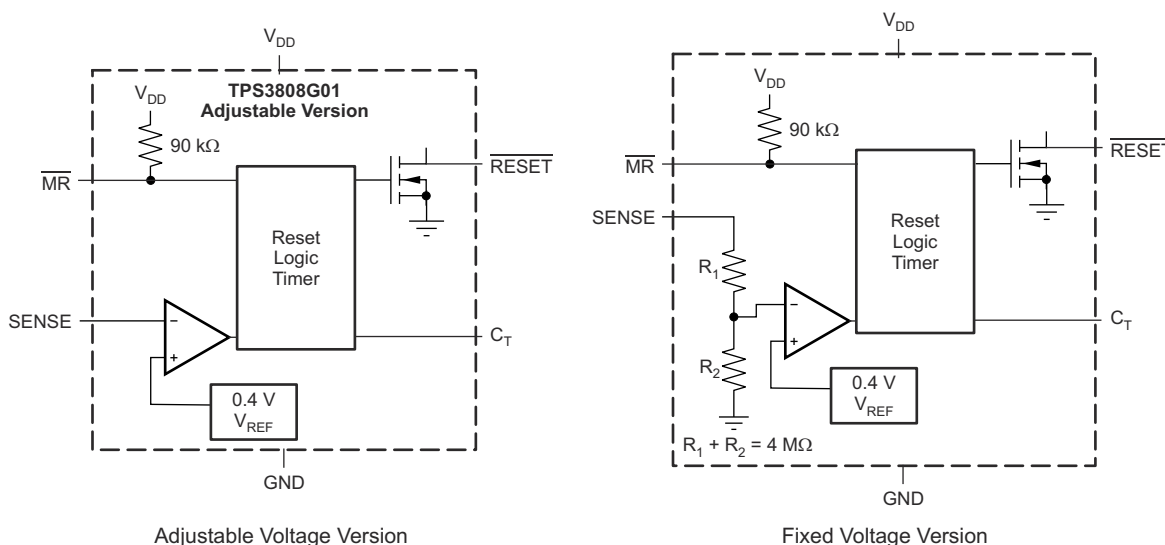
图 7-8. Low-Level $\overline{\text{RESET}}$ Voltage vs $\overline{\text{RESET}}$ Current

8 Detailed Description

8.1 Overview

The TPS3808 microprocessor supervisory product family is designed to assert a $\overline{\text{RESET}}$ signal when either the SENSE pin voltage drops below V_{IT} or the manual reset ($\overline{\text{MR}}$) is driven low. The $\overline{\text{RESET}}$ output remains asserted for a user-adjustable time after both the manual reset ($\overline{\text{MR}}$) and SENSE voltages return above their respective thresholds.

8.2 Functional Block Diagram



8.3 Feature Description

A broad range of voltage threshold and reset delay time adjustments are available for the TPS3808 device, allowing these devices to be used in a wide array of applications. Reset threshold voltages can be factory-set from 0.82 V to 3.3 V or from 4.4 V to 5 V, while the TPS3808G01 can be set to any voltage above 0.405 V using an external resistor divider. Two preset delay times are also user-selectable: connecting the C_T pin to V_{DD} results in a 300-ms reset delay, whereas leaving the C_T pin open yields a 20-ms reset delay. In addition, connecting a capacitor between C_T and GND allows the designer to select any reset delay period from 1.25 ms to 10 s.

8.3.1 SENSE Input

The SENSE input provides a pin at which any system voltage can be monitored. If the voltage on this pin drops below V_{IT} , then $\overline{\text{RESET}}$ is asserted. The comparator has a built-in hysteresis to ensure smooth $\overline{\text{RESET}}$ assertions and de-assertions. It is good analog design practice to put a 1-nF to 10-nF bypass capacitor on the SENSE input to reduce sensitivity to transients and layout parasitics.

The TPS3808 device is relatively immune to short negative transients on the SENSE pin. Sensitivity to transients is dependent on threshold overdrive, as shown in (图 7-5).

The TPS3808G01 can be used to monitor any voltage rail down to 0.405 V using the circuit shown in 图 8-1.

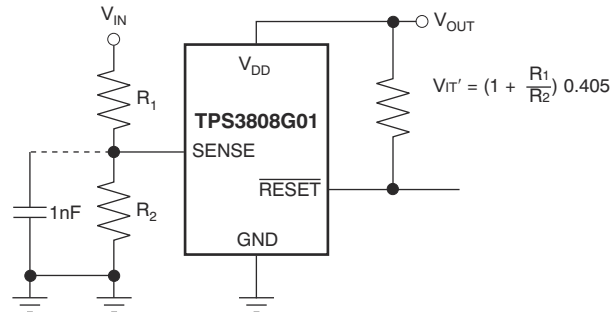


图 8-1. Using the TPS3808G01 to Monitor a User-Defined Threshold Voltage

8.3.2 Selecting the RESET Delay Time

The TPS3808 has three options for setting the $\overline{\text{RESET}}$ delay time as shown in 图 8-2. 图 8-2 (a) shows the configuration for a fixed 300-ms typical delay time by tying C_T to V_{DD} ; a resistor from 40 k Ω to 200 k Ω must be used. Supply current is not affected by the choice of resistor. 图 8-2 (b) shows a fixed 20-ms delay time by leaving the C_T pin open. 图 8-2 (c) shows a ground referenced capacitor connected to C_T for a user-defined program time between 1.25 ms and 10 s.

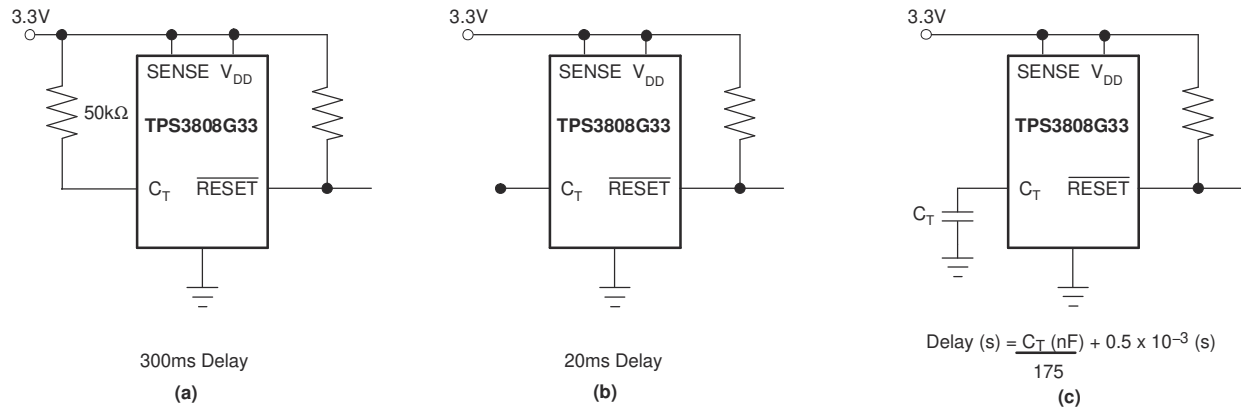


图 8-2. Configuration Used to Set the $\overline{\text{RESET}}$ Delay Time

The capacitor C_T should be ≥ 100 pF nominal value in order for the TPS3808xxx to recognize that the capacitor is present. The capacitor value for a given delay time can be calculated using 方程式 1.

$$C_T (\text{nF}) = [t_D (\text{s}) - 0.5 \times 10^{-3} (\text{s})] \times 175 \quad (1)$$

The reset delay time is determined by the time it takes an on-chip precision 220-nA current source to charge the external capacitor to 1.23 V. When a $\overline{\text{RESET}}$ is asserted, the capacitor is discharged. When the $\overline{\text{RESET}}$ conditions are cleared, the internal current source is enabled and begins to charge the external capacitor. When the voltage on this capacitor reaches 1.23 V, $\overline{\text{RESET}}$ is deasserted. Note that a low-leakage type capacitor such as a ceramic should be used, and that stray capacitance around this pin may cause errors in the reset delay time.

8.3.3 Manual RESET ($\overline{\text{MR}}$) Input

The manual reset ($\overline{\text{MR}}$) input allows a processor or other logic circuits to initiate a reset. A logic low ($0.3 V_{\text{DD}}$) on $\overline{\text{MR}}$ causes $\overline{\text{RESET}}$ to assert. After $\overline{\text{MR}}$ returns to a logic high and SENSE is above its reset threshold, $\overline{\text{RESET}}$ is de-asserted after the user-defined reset delay expires. Note that $\overline{\text{MR}}$ is internally tied to V_{DD} using a 90-k Ω resistor, so this pin can be left unconnected if $\overline{\text{MR}}$ is not used.

See Figure 8-3 for how $\overline{\text{MR}}$ can be used to monitor multiple system voltages. Note that if the logic signal driving $\overline{\text{MR}}$ does not go fully to V_{DD} , there is some additional current draw into V_{DD} as a result of the internal pullup resistor on $\overline{\text{MR}}$. To minimize current draw, a logic-level FET can be used as illustrated in Figure 8-4.

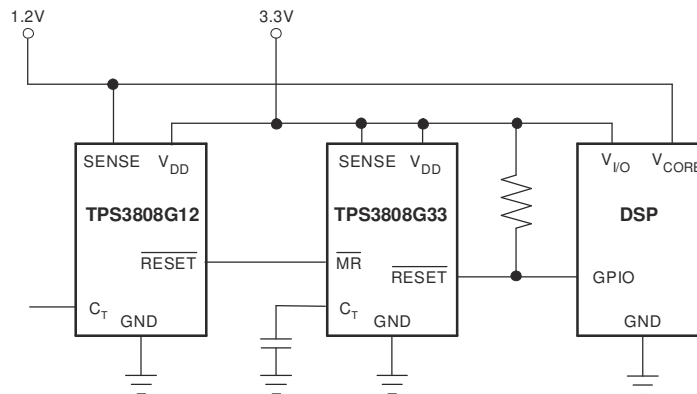


图 8-3. Using $\overline{\text{MR}}$ to Monitor Multiple System Voltages

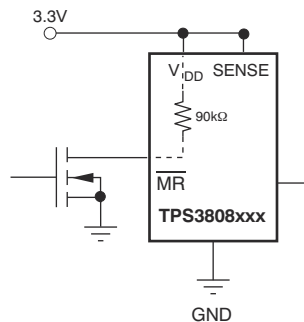


图 8-4. Using an External MOSFET to Minimize I_{DD} When $\overline{\text{MR}}$ Signal Does Not Go to V_{DD}

8.3.4 RESET Output

$\overline{\text{RESET}}$ remains high (unasserted) as long as SENSE is above its threshold (V_{IT}) and the manual reset ($\overline{\text{MR}}$) is logic high. If either SENSE falls below V_{IT} or $\overline{\text{MR}}$ is driven low, $\overline{\text{RESET}}$ is asserted, driving the $\overline{\text{RESET}}$ pin to a low impedance.

Once $\overline{\text{MR}}$ is again logic high and SENSE is above $V_{\text{IT}} + V_{\text{HYS}}$ (the threshold hysteresis), a delay circuit is enabled that holds $\overline{\text{RESET}}$ low for a specified reset delay period. Once the reset delay has expired, the $\overline{\text{RESET}}$ pin goes to a high impedance state. The pullup resistor from the open-drain $\overline{\text{RESET}}$ to the supply line can be used to allow the reset signal for the microprocessor to have a voltage higher than V_{DD} (up to 6.5 V). The pullup resistor should be no smaller than 10 k Ω as a result of the finite impedance of the $\overline{\text{RESET}}$ line.

8.4 Device Functional Modes

表 8-1. Truth Table

MR	SENSE > V _{IT}	RESET
L	0	L
L	1	L
H	0	L
H	1	H

8.4.1 Normal Operation ($V_{DD} > V_{DD(min)}$)

When V_{DD} is greater than $V_{DD(min)}$, the $\overline{RESET}$ signal is determined by the voltage on the SENSE pin and the logic state of $\overline{MR}$.

- $\overline{MR}$ high: When the voltage on V_{DD} is greater than 1.7 V for a time of the selected t_D , the $\overline{RESET}$ signal corresponds to the voltage on SENSE relative to V_{IT} .
- $\overline{MR}$ low: in this mode, $\overline{RESET}$ is held low regardless of the value of the SENSE pin.

8.4.2 Above Power-On Reset but Less Than $V_{DD(min)}$ ($V_{POR} < V_{DD} < V_{DD(min)}$)

When the voltage on V_{DD} is less than the device $V_{DD(min)}$ voltage, and greater than the power-on reset voltage (V_{POR}), the $\overline{RESET}$ signal is asserted and low impedance, respectively, regardless of the voltage on the SENSE pin.

8.4.3 Below Power-On Reset ($V_{DD} < V_{POR}$)

When the voltage on V_{DD} is lower than the required voltage (V_{POR}) needed to internally pull the asserted output to GND, $\overline{RESET}$ is undefined and should not be relied upon for proper device function.

9 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The following sections describe in detail how to properly use this device, depending on the requirements of the final application.

9.2 Typical Application

A typical application of the TPS3808G25 used with a 2.5-V processor is shown in 图 9-1. The open-drain $\overline{\text{RESET}}$ output is typically connected to the $\overline{\text{RESET}}$ input of a microprocessor. A pullup resistor must be used to hold this line high when $\overline{\text{RESET}}$ is not asserted. The $\overline{\text{RESET}}$ output is undefined for voltage below 0.8 V, but this characteristic is normally not a problem because most microprocessors do not function below this voltage.

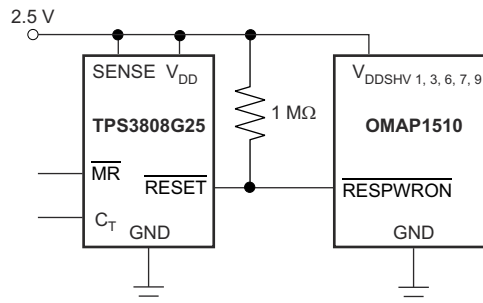


图 9-1. Typical Application of the TPS3808 With an OMAP Processor

9.2.1 Design Requirements

The TPS3808 is intended to drive the $\overline{\text{RESET}}$ input of a microprocessor. The $\overline{\text{RESET}}$ pin is pulled high with a 1-MΩ resistor and the reset delay time is controlled by C_T depending on the reset requirement times of the microprocessor. In this case, C_T is left open for a typical reset delay time of 20 ms.

9.2.2 Detailed Design Procedure

The primary constraint for this application is the reset delay time. In this case, because C_T is open, it is set to 20 ms. A 0.1-μF decoupling capacitor is connected to the V_{DD} pin and a 1-MΩ resistor is used to pull up the $\overline{\text{RESET}}$ pin high. The $\overline{\text{MR}}$ pin can be connected to an external signal if desired.

9.2.2.1 Immunity to SENSE Pin Voltage Transients

The TPS3808 is relatively immune to short negative transients on the SENSE pin. Sensitivity to transients depends on threshold overdrive. Threshold overdrive is defined by how much the V_{SENSE} exceeds the specified threshold, and is important to know because the smaller the overdrive, the slower the $\overline{\text{RESET}}$ response. Threshold overdrive is calculated as a percent of the threshold in question, as shown in 方程式 2:

$$\text{Overdrive} = | (V_{\text{SENSE}} / V_{\text{IT}} - 1) \times 100\% | \quad (2)$$

where:

- V_{IT} is the threshold voltage.

图 9-2 shows this relationship.

9.2.3 Application Curve

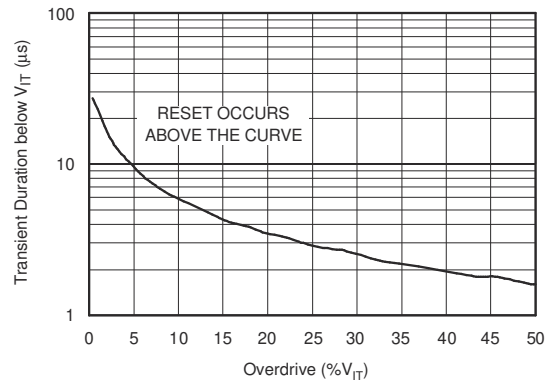


图 9-2. Maximum Transient Duration at SENSE vs SENSE Threshold Overdrive Voltage

10 Power Supply Recommendations

These devices are designed to operate from an input supply with a voltage range between 1.7 V and 6.5 V. Use a low-impedance power supply to eliminate inaccuracies caused by current changes during the voltage reference refresh.

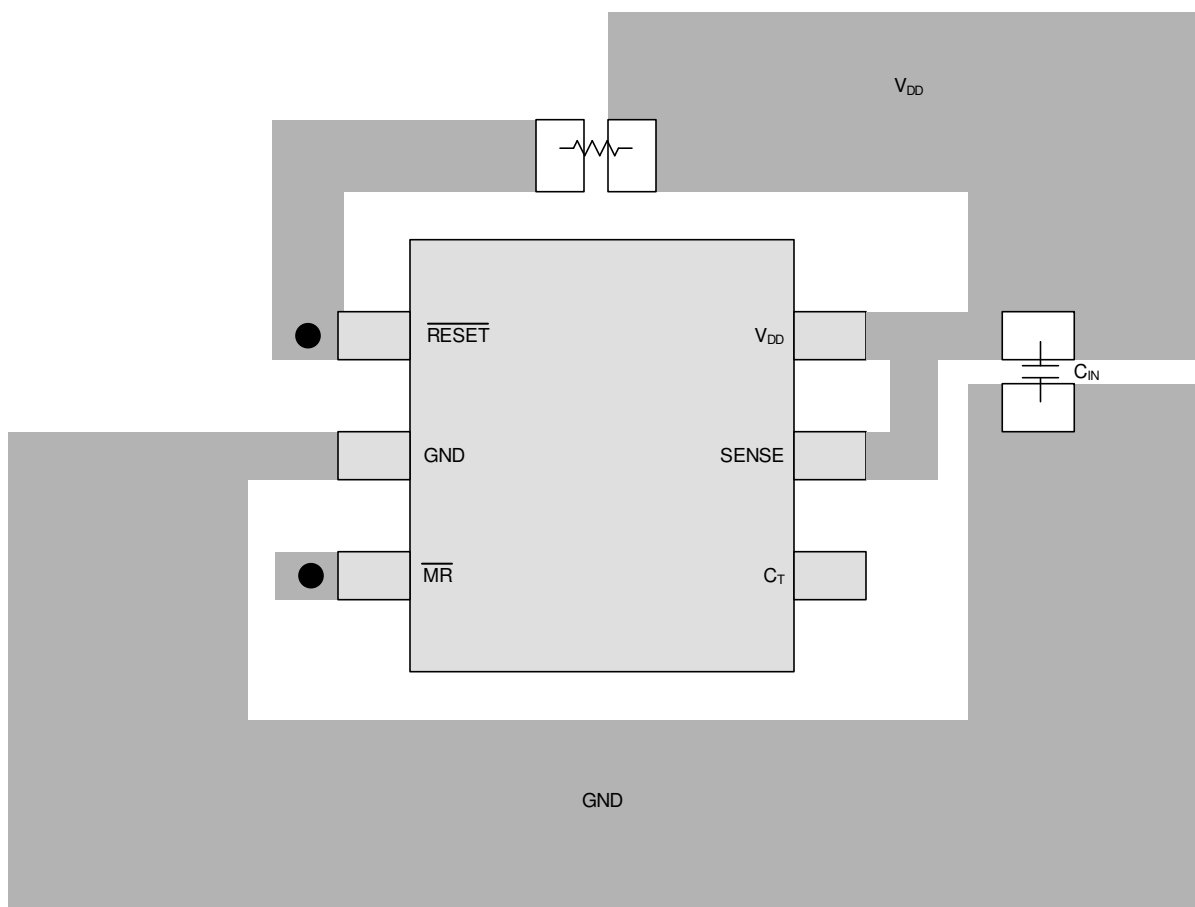
11 Layout

11.1 Layout Guidelines

Make sure the connection to the V_{DD} pin is low impedance. Place a 0.1-μF ceramic capacitor near the V_{DD} pin. If no capacitor is connected to the C_T pin, parasitic capacitance on this pin should be minimized so the RESET delay time is not adversely affected.

11.2 Layout Example

The layout example in 图 11-1 shows how the TPS3808 is laid out on a printed circuit board (PCB) for a 20-ms delay.



● Vias used to connect pins for application-specific connections

11-1. Layout Example for a 20-ms Delay

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS3808. The [TPS3808G01DBVEVM evaluation module](#) (and related [user guide](#)) can be requested at the Texas Instruments website through the product folders or purchased directly from the [TI eStore](#).

12.2 Documentation Support

12.2.1 Related Documentation

The following related documents are available for download at www.ti.com:

- Application note. *Optimizing Resistor Dividers at a Comparator Input*. Literature number [SLVA450](#).
- Application note. *Sensitivity Analysis for Power Supply Design*. Literature number [SLVA481](#).
- TPS3808G01DBVEVM Evaluation Module User Guide. Literature number [SBVU015](#).

12.3 支持资源

[TI E2E™ 支持论坛](#)是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

12.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

12.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS3808G01DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G01DRVVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVW
TPS3808G09DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G09DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVV
TPS3808G125DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G125DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAC
TPS3808G12DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G12DRVVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVY
TPS3808G15DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DBVRG4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G15DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G15DRVVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVS
TPS3808G18DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G18DRVVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVR
TPS3808G19DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G19DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CHP
TPS3808G25DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AVQ, EG25)
TPS3808G25DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DRVR	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G25DRVVT	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVQ
TPS3808G30DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVP

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS3808G30DRV	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G30DRV	Active	Production	WSO (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AVP
TPS3808G33DBV	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3808G33DBV	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVO
TPS3808G33DRV	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G33DRV	Active	Production	WSO (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SEC
TPS3808G50DBV	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN
TPS3808G50DBV	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AVN

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF TPS3808 :

- Automotive : [TPS3808-Q1](#)
- Enhanced Product : [TPS3808-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3808G01DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G01DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G01DRVR	WSO	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G01DRVT	WSO	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G01DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G09DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G09DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G125DBVR	SOT-23	DBV	6	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G125DBVT	SOT-23	DBV	6	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G12DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G12DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G12DRVR	WSO	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G12DRVT	WSO	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G12DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G15DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G15DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3808G15DRVR	WSO	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G15DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G18DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G18DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G18DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G19DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G19DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G25DRVR	WSO	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G25DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G30DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G30DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G30DBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS3808G30DRVR	WSO	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G30DRVR	WSO	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G30DRVT	WSO	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS3808G30DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G33DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G33DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G33DRVR	WSO	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G33DRVT	WSO	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS3808G50DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3808G50DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3808G01DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G01DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G01DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G01DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G01DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G09DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G09DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G125DBVR	SOT-23	DBV	6	3000	200.0	183.0	25.0
TPS3808G125DBVT	SOT-23	DBV	6	250	200.0	183.0	25.0
TPS3808G12DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G12DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G12DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G12DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G12DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G15DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G15DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G15DRVR	WSON	DRV	6	3000	200.0	183.0	25.0
TPS3808G15DRVT	WSON	DRV	6	250	200.0	183.0	25.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3808G18DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G18DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G18DRV	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G19DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G19DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G25DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G25DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G25DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS3808G25DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G30DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS3808G30DBVT	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G30DBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TPS3808G30DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS3808G30DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS3808G30DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS3808G30DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS3808G33DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G33DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TPS3808G33DRVR	WSON	DRV	6	3000	200.0	183.0	25.0
TPS3808G33DRVT	WSON	DRV	6	250	200.0	183.0	25.0
TPS3808G50DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3808G50DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



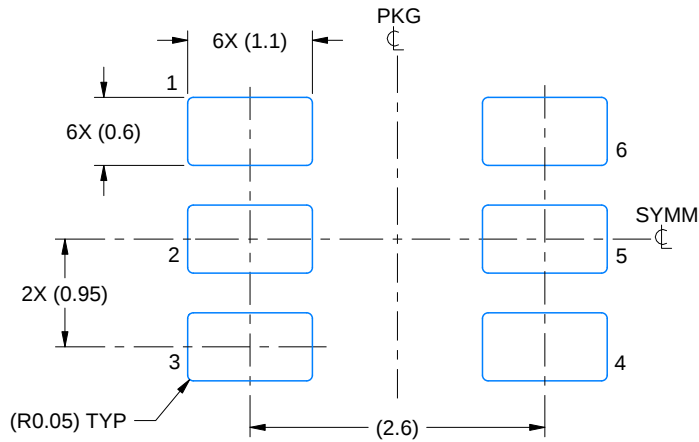
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

EXAMPLE BOARD LAYOUT

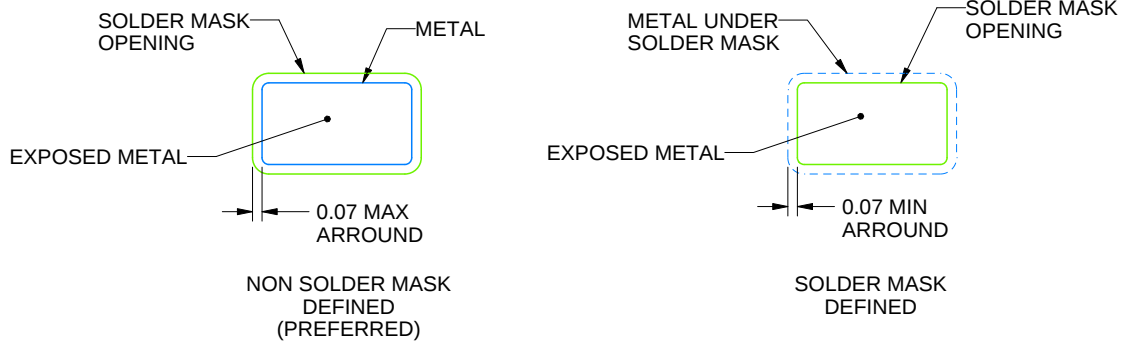
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

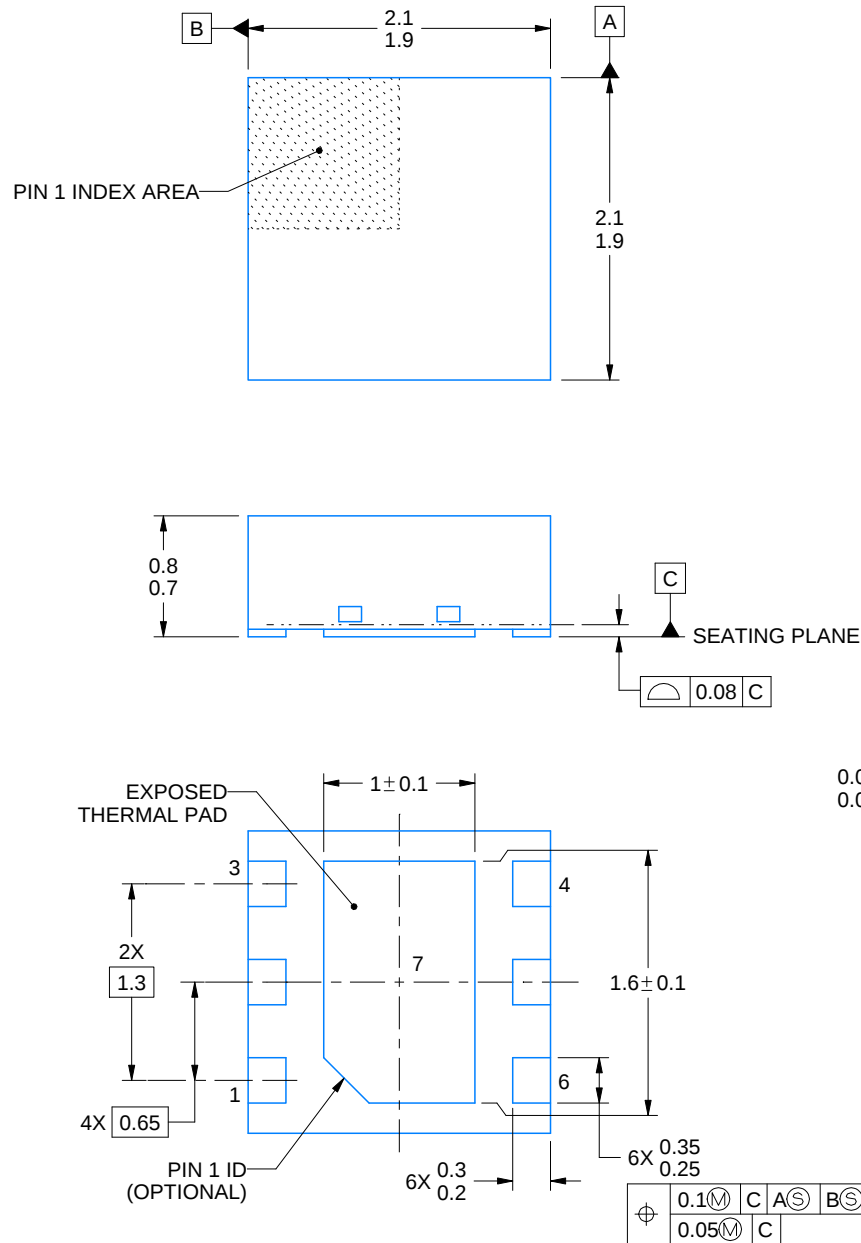
4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4222173/B 04/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

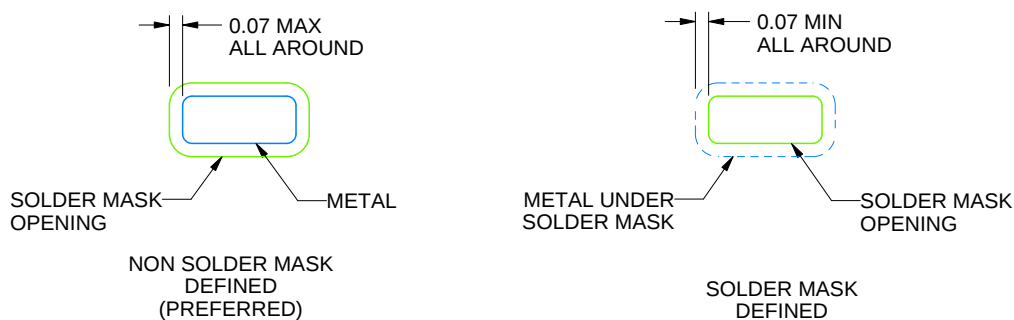
DRV0006A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:25X



SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slue271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006A

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



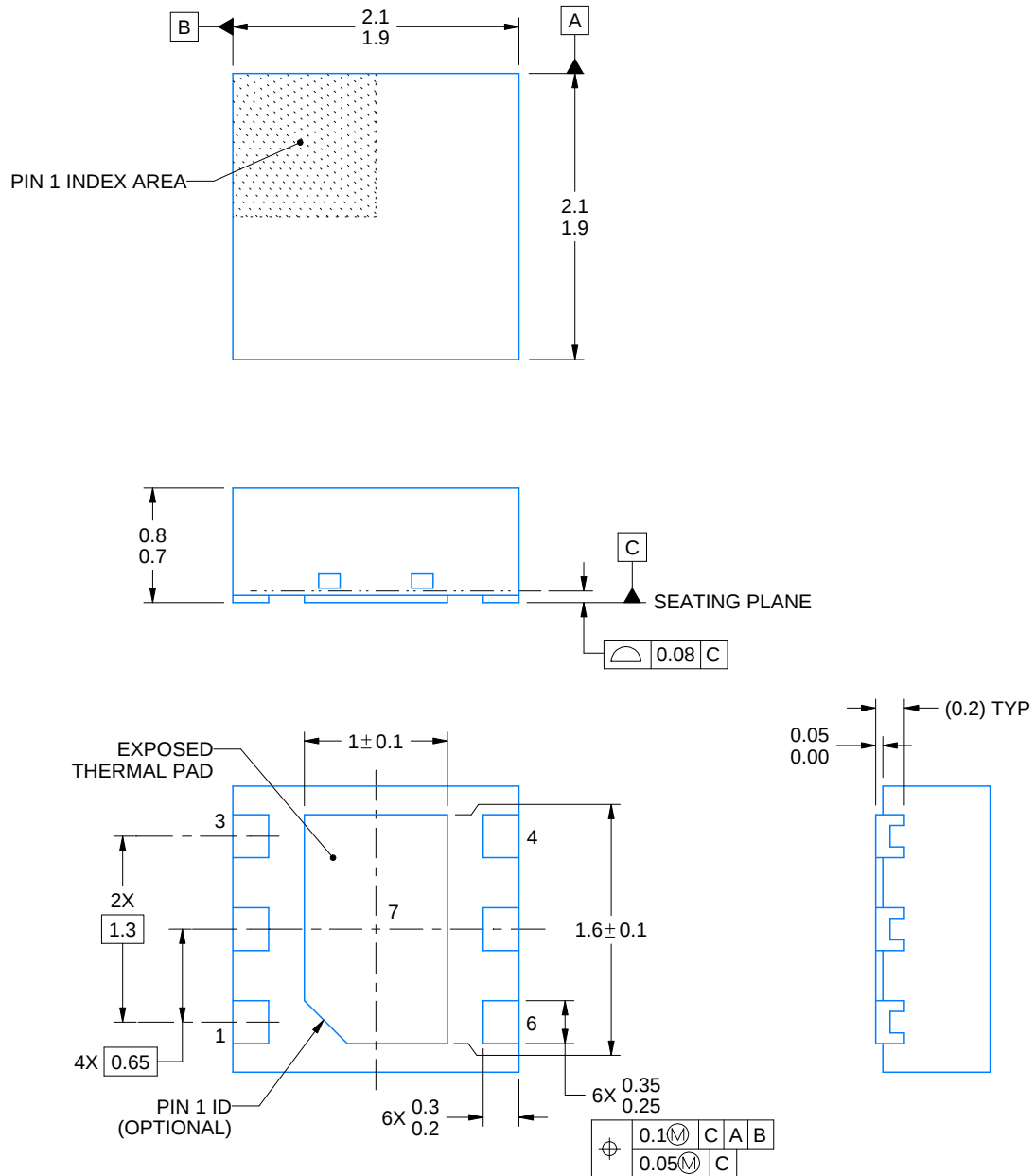
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4222173/B 04/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4225563/A 12/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

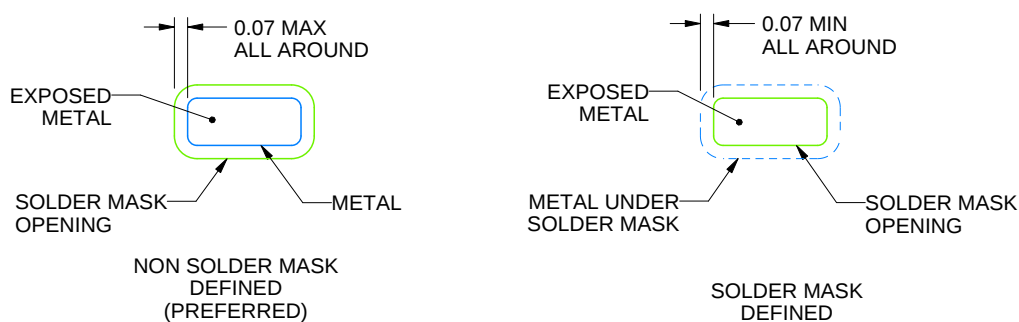
DRV0006D

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



SOLDER MASK DETAILS

4225563/A 12/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006D

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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